

4-bit Bidirectional Voltage-Level Translator for Open-Drain and Push-Pull Applications

Features

- Voltage Level Translator Without Direction-Control Signal
- Maximum Data Rates
 - 24Mbps (Push Pull)
 - 2Mbps (Open Drain)
- Power Supply Range:
 - A Port and VCCA: 1.1V to 3.6 V
 - B Port and VCCB: 1.65 V to 5.5 V
 - VCCA ≤ VCCB
- Pull Up Resistors are Integrated in A Port and B Port
- No Power-Supply Sequencing Required: Either VCCA or VCCB Can be Ramped First
- Support Ultra-Low Power Consumption Mode with OE Pin is Low Voltage Level
- Latch -Up Performance Exceeds ±200mA Under JESD 78 Standard
- WBQFN 1.8mm×1.8mm×0.55mm -12L Package

General Description

AW39114A is a 4-bit high-performance voltage-level translator without direction control signal, which is a non-inverting converter and can be used to convert digital signal with mixed-voltage systems. It needs two separate power supply rails, with the A ports tracks the $V_{\rm CCA}$ ranging from 1.1V to 3.6 V, and the B ports tracks the $V_{\rm CCB}$ ranging from 1.65 V to 5.5 V. This makes the chip has capabilities of support both lower and higher logic signal levels translation between any of the 1.2V, 1.8 V, 2.5 V, 3.3 V, and 5 V voltage nodes.

The OE input circuit is supplied by VCCA. Meanwhile, OE is recommended to be tied to GND through an external pull-down resistor to ensure all I/O to be pulled to the supply voltage. No power supply sequencing requirements means either VCCA or VCCB can be powered up first, and OE should be enabled after both VCCA and VCCB are established.

Applications

- I²C / SMBus
- UART
- GPIO
- Handheld Devices Interface

Application Circuit

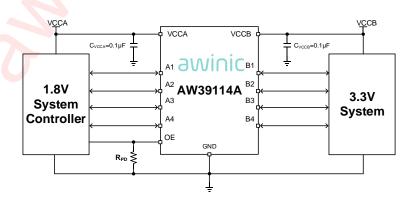


Figure 1 Typical Application Circuit of AW39114A

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Pin Configuration and Top Mark

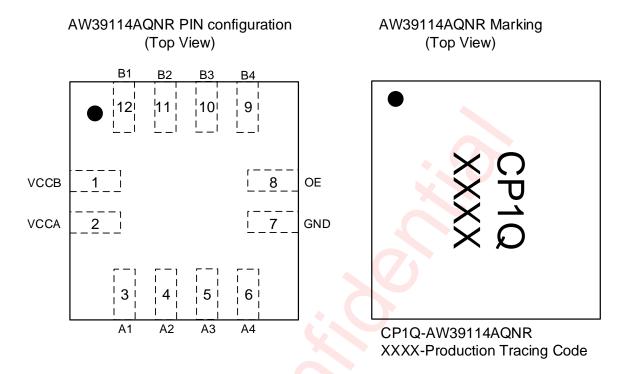


Figure 2 Pin Configuration and Top Mark

Pin Definition

Pin No.	Pin Name	Description
1	VCCB	B-port supply voltage. 1.65 V ≤ VCCB ≤ 5.5 V.
2	VCCA	A-port supply voltage. 1.1 V ≤ VCCA ≤ 3.6 V, VCCA ≤ VCCB.
3	A1 🔷	Input/output A1.
4	A2	Input/output A2.
5	A3	Input/output A3.
6	A4	Input/output A4.
7	GND	Ground.
8	OE	Output enable.
9	B4	Input/output B4.
10	B3	Input/output B3.
11	B2	Input/output B2.
12	B1	Input/output B1.

Functional Block Diagram

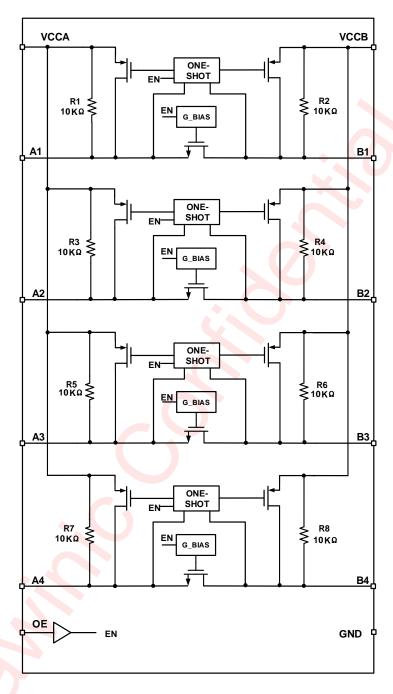


Figure 3 AW39114A Function Block



Typical Application Circuits

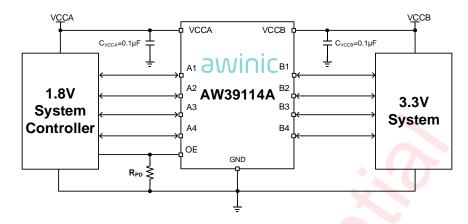


Figure 4 AW39114A Application Circuit

Notice for typical application circuits:

- 1. In any case, the A/B Ports Voltage cannot be higher than the VCCA/VCCB voltage. Otherwise, the leakage current will flow from A/B Ports to VCCA/VCCB.
- 2. The device driving the A/B ports must have the driving capacity at least ±1 mA.

Ordering Information

Part Number	Temperature	Package	Marking	Moisture Sensitivity Level	Environmenta I Information	Delivery Form
AW39114AQNR	-40°C∼85°C	WBQFN 1.8mm×1.8mm×0.55 mm -12L	CP1Q	MSL1	RoHS+HF	3000 units/ Tape and Reel



Absolute Maximum Ratings(NOTE1)

PARAMETERS		MIN	MAX	UNIT
Supply voltage range V _{CCA} (NOTE2	2)	-0.5	5	V
Supply voltage range V _{CCB} (NOTE	2)	-0.5	6.5	V
Input voltage range, V _I ^(NOTE2)	A port	-0.5	5	V
input voltage range, Vivole29	B port -0.5 high or low state, $V_O^{(NOTE2)}$ A port -0.5	6.5	V	
Output valte as a series in high an law state V (NOTE2)	A port	-0.5	5	V
Output voltage range in high or low state, vo	B port	-0.5	6.5	V
Input clamp current, I _{lk}	V _I <0		-50	mA
Output clamp current, Іок	Vo<0		-50	mA
Operating free-air temperature rai	nge	-40	85	°C
Operating junction temperature	-40	125	°C	
Storage temperature T _{STG}	Storage temperature T _{STG}			°C
Lead temperature (Soldering 10 sec	conds)		260	°C

NOTE1: Conditions out of those ranges listed in "absolute maximum ratings" may cause permanent damages to the device. In spite of the limits above, functional operation conditions of the device should within the ranges listed in "recommended operating conditions". Exposure to absolute-maximum-rated conditions for prolonged periods may affect device reliability.

NOTE2: With respect to GND.

ESD Rating and Latch Up

PARAMETERS	VALUE	UNIT
HBM (Human Body Model) (NOTE 3)	±2	kV
CDM(NOTE 4)	±1.5	kV
Latch-Up ^(NOTE 5)	+IT: 200 -IT: -200	mA

NOTE3: The human body model is a 100pF capacitor discharged through a 1.5k Ω resistor into each pin.

Test method: ESDA/JEDEC JS-001-2017

NOTE4: Test method: ESDA/JEDEC JS-002-2018

NOTE5: Test method: JESD78E

Recommended Operating Conditions

VCCI is the VCC associated with the input port

	PARAMETERS	CON	DITIONS	MIN	MAX	UNIT
V _{CCA}	Supply voltage for A port			1.1	3.6	V
Vccв	Supply voltage for B port			1.65	5.5	V
		A mout	V _{CCA} =1.1V~1.95V V _{CCB} =1.65V~5.5V	Vcci-0.3	Vccı	V
V _{IH}		A-port	V _{CCA} =2.3V~3.6V V _{CCB} =1.65V~5.5V	V _{CCI} -0.4	V _{CCI}	V
	High-level input voltage	B-port	V _{CCA} =1.1V~3.6V V _{CCB} =1.65V~5.5V	V _{CCI} -0.4	V _{CCI}	V
		OE input	V _{CCA} =1.1V~3.6V V _{CCB} =1.65V~5.5V	Vcca×0.65	5.5	V
		A-port	V _{CCA} =1.1V~3.6V V _{CCB} =1.65V~5.5V	0	0.15	V
V_{IL}	Low-level input voltage	B-port	V _{CCA} =1.1V~3.6V V _{CCB} =1.65V~5.5V	0	0.15	V
		OE input	V _{CCA} =1.1V~3.6V V _{CCB} =1.65V~5.5V	0	V _{CCA} ×0.35	V
		A-port (NOTE6)	V _{CCA} =1.1V~3.6V V _{CCB} =1.65V~5.5V		10	ns/V
Δt/ΔV	Input transition rise or fall rate	B-port (NOTE6)	V _{CCB} =1.1V~3.6V V _{CCB} =1.65V~5.5V		10	ns/V
		Control input	V _{CCA} =1.1V~3.6V V _{CCB} =1.65V~5.5V		10	ns/V
T _A	Operating junction temper	ature T _A		-40	85	°C

NOTE6: The parameter is defined for push-pull driving.

Thermal Information

PARAMETERS	VALUE	UNIT
Junction-to-ambient thermal resistance θ _{JA}	120	°C /W



Electrical Characteristics

DC Electrical Characteristics

Operating under recommended conditions, VCCA ≤ VCCB, T_A=25°C for typical values (unless otherwise noted)

P/	ARAMETER	TEST CONDITION	V _{CCA} (V)	V _{CCB} (V)	MIN	TYP	MAX	UNIT
Vона	Port A output high voltage	I _{OH} = -20μA V _{IB} ≥V _{CCB} -0.4V			Vcca×0.67			V
Vola	Port A output low voltage	I _{OL} =1mA V _{IB} ≤0.15V			. (?)		0.4	V
Vонв	Port B output high voltage	I _{OH} = -20μA V _{IA} ≥V _{CCA} -0.2V			V _{CCB} ×0.67			V
Volb	Port B output low voltage	I _{OL} =1mA V _{IA} ≤0.15V	1.1~3.6	1.65~5.5			0.4	V
I.	OE input	V _I =V _{CCI} or GND, T _A =25°C	1.1~3.0	1.05~5.5	-1		1	μΑ
l _l	leakage current	V _I =V _{CCI} or GND, T _A =-40°C to 85°C			-2		2	μΑ
loz	A or B port	OE=V _{IL} V _I =GND, T _A =-40°C to 85°C			-2		2	μA
102	output current	OE=V _{IL} V _I = V _{CCI} , T _A =-40°C to 85°C			-1		1	μA
		$\begin{array}{c} \text{OE=V}_{\text{IH}} \\ \text{V}_{\text{I}} = \text{V}_{\text{O}} = \text{Open, I}_{\text{O}} = 0, \\ \text{T}_{\text{A}} = 25^{\circ}\text{C} \\ \\ \text{OE=V}_{\text{IH}} \\ \text{V}_{\text{I}} = \text{V}_{\text{O}} = \text{Open, I}_{\text{O}} = 0, \\ \end{array}$	1.1~3.6	1.65~5.5			1	μA
	VCCA supply current		3.6	0			1	μA
Icca			0	5.5			-1	μA
ICCA			3.6	5.5		0.04		μΑ
			3.6	0		0.03		μΑ
		T _A = 85°C	0	5.5		-0.03		μΑ
		OE=V _{IH}	1.1~3.6	1.65~5.5			16	μΑ
		V _I =V _O =Open, I _O =0,	3.6	0			-1	μΑ
Іссв	VCCB supply	T _A =25°C	0	5.5			1	μΑ
ICCB	current	OE=V _{IH}	3.6	5.5		4.3		μΑ
		V _I =V _O =Open, I _O =0,	3.6	0		-0.01		μΑ
		T _A = 85°C	0	5.5		0.09		μΑ
I _{CCB} + I _{CCA}	Combined supply current	V _I =V ₀ =Open I ₀ =0	1.1~3.6	1.65~5.5			18	μΑ
R _{PU}	Resistor pull-up value	T _A =25°C	1.1~3.6	1.65~5.5	8	10	12	kΩ
RNPASS	The resistor of NMOSFET between A port and B port	OE=V _{IH} ,V _I =0.15V I _{source} =10mA, T _A =25°C	1.8	3.3		25		Ω



Timing Requirements (NOTE1)

Output load: C_L=15pF, push-pull driver, and T_A=-40°C to 85°C.

PAF	RAMETER	TEST CONDITION	MIN	MAX	UNIT
V _{CCA} =1.1V±0.	15V / 2.5V±0.2V / 3.3V	/±0.3V			
		V _{CCB} =1.8V±0.2V		21	
Data Rate		V _{CCB} =3.3V±0.3V		24	Mbps
		V _{CCB} =5V±0.5V		24	
		V _{CCB} =2.5V±0.2V	45		
t _w	Pulse Duration	V _{CCB} =3.3V±0.3V	40		ns
		V _{CCB} =5V±0.5V	40		

NOTE1: The parameter's variation is guaranteed by design, not production tested.

Switch Characteristics

Output load: C_L=15pF, T_A=25°C for typical values (unless otherwise noted), V_{CCA}=1.1V

DADAMETED	TEST CONDITION		V _{CCB} =1.65V	V _{CCB} =3.3V	V _{CCB} =5V	LINUT
PARAMETER			TYP	TYP	TYP	UNIT
t _{PHL} (NOTE2)	A to B	Push-pull	12	17.9	23.5	no
THEY ?	ALUB	Open-drain	8.6	13.5	18.8	ns
t _{PLH} (NOTE2)	A to B	Push-pull	18.8	15.7	15.2	20
LPLH((10 122)	A 10 B	Open-drain	27.3	26.4	19.4	ns
t _{PHL} (NOTE2)	D to A	Push-pull	3.6	3.2	2.8	no
TPHL ^(NOTE2)	B to A	Open-drain	4.7	3.5	3.7	ns
t _{PLH} (NOTE2)	B to A	Push-pull	8.7	2.7	1.8	20
(PLH((***)*****)		Open-drain	0.5	0.8	0.8	ns
t _{en} Enable time	OE to A or B		31	14.8	12.8	ns
t _{dis} disable time	OE to A or B		139.8	161	97	ns
t . output rice time	A part rise time	Push-pull	24.3	15.3	8.9	20
t _{rA} output rise time	A port rise time	Open-drain	162.4	106.3	76.2	ns
t - output rice time	B port rise time	Push-pull	35.6	24.2	17.1	20
t _{rB} output rise time	b port rise time	Open-drain	141.2	65.5	30.9	ns
to output fall time	A port fall time	Push-pull	6.4	5.3	3.1	no
t _{fA} output fall time	A port fail time	Open-drain	5.6	4.6	4.2	ns
to output fall time	P port fall time	Push-pull	15	25.8	37.5	no
t _{fB} output fall time	B port fall time	Open-drain	12.3	21.8	31.4	ns
t _{SK} Skew time output	Channel to channe	el skew	4.9	4.7	4.3	ns

Output load: C_L=15pF, T_A=25°C for typical values (unless otherwise noted), V_{CCA}=1.8V.

PARAMETER	TEST CONDITION		V _{CCB} =1.8V	V _{CCB} =3.3V	V _{CCB} =5V	UNIT
PARAMETER			TYP	TYP	TYP	UNIT
t _{PHL} (NOTE2)	A to B	Push-pull	1.4	2.3	3.2	no
	Open-drain	3.6	4	4.7	ns	
t _{PLH} (NOTE2)	A to B	Push-pull	2.1	3.2	3.3	
IPLH(************************************		Open-drain	0.1	0.2	0.3	ns
4 (NOTE2)	I R to A	Push-pull	3.1	2.3	1.8	ns
t _{PHL} (NOTE2)		Open-drain	2.4	1.9	2	



PARAMETER	TEST CONDITION		V _{CCB} =1.8V	V _{CCB} =3.3V	V _{CCB} =5V	UNIT
PARAMETER	TEST CON	NDITION	TYP	TYP	TYP	UNII
(NOTE2)	D to A	Push-pull	4	2.3	1.7	20
t _{PLH} ^(NOTE2)	B to A	Open-drain	-0.19	-0.28	-0.38	ns
t _{en} Enable time	OE to A or B		21	10.7	7.2	ns
t _{dis} disable time	OE to A or B		138	152.7	156.5	ns
t autout via a time a	A port rise time	Push-pull	10.2	4.5	4.1	
t _{rA} output rise time		Open-drain	118.4	77.3	56.2	ns
t and and also times	5	Push-pull	8.2	5.6	4.7	
t _{rB} output rise time	B port rise time	Open-drain	125.3	60.3	29.4	ns
t autout fall times	A	Push-pull	5.9	2.5	1.4	
t _{fA} output fall time	A port fall time	Open-drain	4.5	3.9	3.5	ns
t autaut fall time	D mant fall time a	Push-pull	3.7	4.2	5.4	
t _{fB} output fall time	B port fall time	Open-drain	6.6	6.8	7.7	ns
tsk Skew time output	Channel to chann	el skew	0.8	0.7	0.7	ns

Output load: C_L=15pF, T_A=25°C for typical values (unless otherwise noted), V_{CCA}=2.5V

PARAMETER	TEST CONDITION		V _{CCB} =2.5V	V _{CCB} =3.3V	V _{CCB} =5V	UNIT	
PANAMETER	1231 001	TEST CONDITION		TYP	TYP	ONIT	
t _{PHL} (NOTE2)	A	Push-pull	1.6	1.7	1.9	no	
IPHL(************************************	A to B	Open-drain	1.8	2	2.8	ns	
+(NOTF2)	A to B	Push-pull	1.7	2.2	2.4	no	
t _{PLH} (NOTE2)	AIUD	Open-drain	0.1	0.1	0.2	ns	
t _{PHL} (NOTE2)	B to A	Push-pull	2	1.8	1.6	20	
	D IO A	Open-drain	1	1.3	1.3	ns	
t _{PLH} (NOTE2)	B to A	Push-pull	2.2	1.7	1.4	ns	
		Open-drain	-0.1	-0.1	-0.2		
t _{en} Enable time	OE to A or B		11.6	9.1	7.3	ns	
t _{dis} disable time	OE to A or B		143.4	152.4	154.9	ns	
t . output rico timo	A mant via a time	Push-pull	4.4	3.7	2.9	ne	
t _{rA} output rise time	A port rise time	Open-drain	88.7	74.1	54.5	ns	
t _{rB} output rise time	B port rise time	Push-pull	4.6	4.1	3.6	ns	
irs output rise time	b port rise time	Open-drain	91.8	67.1	37.2	115	
to output fall time	A part fall time	Push-pull	2.9	2.6	2.4	20	
t _{fA} output fall time	A port fall time	Open-drain	3.8	3.3	2.6	ns	
t _{fB} output fall time	B port fall time	Push-pull	2.7	3.2	3.4	ne	
tis output fail time	b port fail tille	Open-drain	3.8	4	5.1	ns	
tsk Skew time output	Channel to chann	el skew	0.8	0.8	0.9	ns	

Output load: $C_L=15pF$, $T_A=25$ °C for typical values (unless otherwise noted), $V_{CCA}=3.3V$

PARAMETER	TEST CON	DITION	V _{CCB} =3.3V	V _{CCB} =5V	UNIT	
PARAMETER	TEST CONDITION		TYP	TYP	UNIT	
t _{PHL} (NOTE2)	A to B	Push-pull	1	1.5	no	
		Open-drain	0.9	1.4	ns	
t _{PLH} (NOTE2)	A to B	Push-pull	1.7	1.8	ns	
IPLH*******		Open-drain	0.1	0.2		



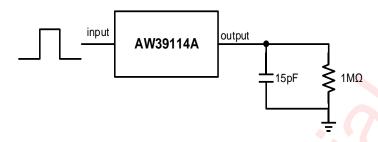
DADAMETED	TEOT 00	NDITION	V _{CCB} =3.3V	V _{CCB} =5V		
PARAMETER	TEST CO	NUITION	TYP	TYP	UNIT	
↓ (N∩TF2)	D to A	Push-pull	1.7	1.6		
t _{PHL} (NOTE2)	B to A	Open-drain	0.5	1.2	ns	
t _{PLH} (NOTE2)	D to A	Push-pull	1.8	1.4		
	B to A	Open-drain	0.1	-0.1	ns	
t _{en} Enable time	OE to A or B		7.9	6.9	ns	
t _{dis} disable time	OE to A or B		148.1	159.7	ns	
((A section Con-	Push-pull	3.3	2.8		
t _{rA} output rise time	A port rise time	Open-drain	69.3	51.8	ns	
to a to take the	B port rise time	Push-pull	3.7	3.3		
t _{rB} output rise time		Open-drain	72.6	43.1	ns	
t _{fA} output fall time	A port fall time	Push-pull	2.6	2.4		
		Open-drain	3.4	3.1	ns	
t _{fB} output fall time	Day (GILC)	Push-pull	Push-pull 2.5			
	B port fall time	Open-drain	3.4	3.6	ns	
tsk Skew time output	Channel to chann	nel skew	1.2	1.1	ns	

NOTE2: tPHL presents propagation delay from high to low, and tPLH presents propagation delay from low to high.



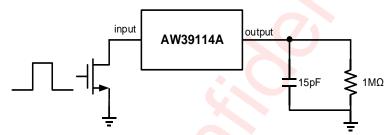
Typical Characteristics

Test Information



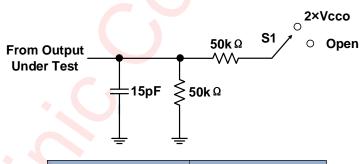
Test Circuit for Date Rate, Pulse Duration, Propagation Delay, Rise Time and Fall Time

Figure 5 Load Circuit of Push-Pull Driver



Test Circuit for Date Rate, Pulse Duration, Propagation Delay, Rise Time and Fall Time

Figure 6 Load Circuit of Open-Drain Driver

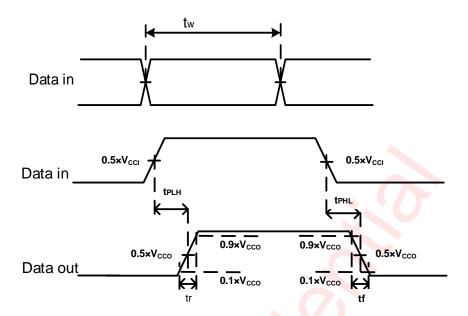


TEST	S1
t _{PZL} /t _{PLZ} (t _{dis})	2 × V _{cco}
t _{PHZ} /t _{PZH} (t _{en})	Open

- 1. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
- 2. t_{PZL} and t_{PZH} are the same as t_{en} .
- 3. VCCI is the VCC associated with the input port.
- 4. VCCO is the VCC associated with the output port.
- 5. The resistance and Capacitance values at output notes above are the total effective values.

Figure 7 Load Circuit for Enable-Time and Disable-Time Measurement

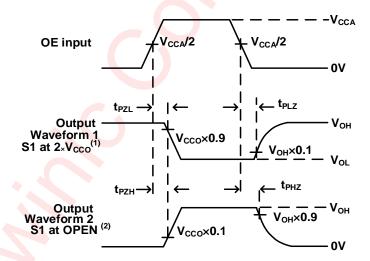




The input pulses should have the following characteristics:

- 1. f_{IN} ≤10MHz.
- 2. dv/dt ≥ 1V/ns.

Figure 8 Timing Parameter Definition



- (1) The Waveform 1 is obtained under the condition that the input is low and S1 at 2*Vcco.
- (2) The Waveform 2 is obtained under the condition that the input and S1 at OPEN.

Figure 9 Enable and Disable Times



Typical Curve T_A=25°C

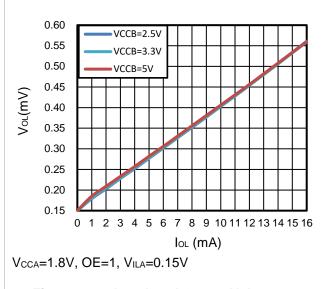
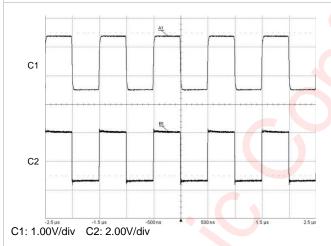


Figure 10 Low-Level Output Voltage vs Low-Level Current



V_{CCA}=1.8V, V_{CCB}=3.3V, OE=1, Push-Pull Driver Signal is translated from A port to B port

Figure 12 Level Translation of a 1MHz Signal

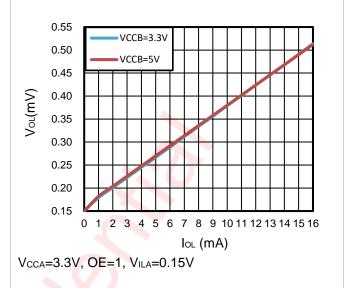
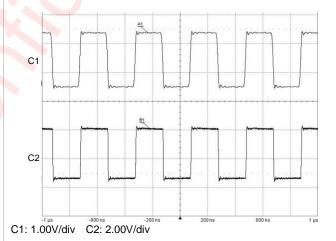


Figure 11 Low-Level Output Voltage vs Low-Level Current



 V_{CCA} =1.8V, V_{CCB} =3.3V, OE=1, Push-Pull Driver Signal is translated from A port to B port

Figure 13 Level Translation of a 2.5MHz Signal



Detailed Functional Description

AW39114A is a 4-bit high-performance voltage-level translator without direction control signal, which is a non-inverting converter and can be used to convert digital signal with mixed-voltage systems. Port A can support I/O voltages from 1.1 V to 3.6 V, while Port B is able to support I/O voltage range from 1.65 V to 5.5 V. The chip uses a transmission gate architecture with an rising edge rate accelerator (one-shot), to increase overall data rate. Also, $10k\Omega$ pull-up resistors are integrated in the chip, which ensures the chip not only supports push-pull applications but also can be used in open-drain applications directly.

One-shot Accelerator

The One-Shot rising edge accelerator circuit speeds up the rising edge to help increasing the chip's data rate. Once the chip has detected the rising edge of the input signal from low to high, the one-shot circuit generates a pulse signal of approximately 30ns, which enables the internal pull-up PMOS transistor between power supply and output, thereby accelerating the output port from low to high. During this acceleration phase, the output resistance of the driver is reduced from $10k\Omega$ to approximately 60Ω . While detecting the output has been turned up, the one-shot pulse signal is finished and pull-up PMOS transistor is quickly turned off. This architecture reduces the average dynamic power consumption of the chip while allowing it to meet different drive requirements.

Gate Bias

For the bidirectional voltage translator AW39114A, a NMOS switch transistor is used between the input and output. When translating high level, the NMOS transistor is turned off, and the input and output terminals are isolated so that they do not impact each other. When the low level is translated, the NMOS switch transistor is fully turned on, so that the output terminal can be quickly pulled down to the low voltage level. Therefore, the gate bias voltage of the NMOS switch transistor is set to a fixed value about VCCA+VTH. It is also because of this architecture that VCCA≤VCCB needs to be guaranteed in the applications.

Enable Control

The AW39114A's OE pin can disable the chip by setting OE to low voltage level, allowing all I/O to be pulled to the supply voltage through a $5M\Omega$ internal pull-up resistor. he disable time (t_{dis}) represents the delay time from OE going low to the chip turns to OFF-state. And the enable time (t_{en}) indicates the delay from OE going high to the chip working in translation state. Meanwhile, OE is recommended to be tied to GND through an external pull-down resistor to ensure the ultra-low power-supply quiescent current. The minimum value of the resistor is determined by the current-sourcing capability of the driver.

Input Driver

The rising edge time of the signal (t_{rA} , t_{rB}) and propagation delay from low to high (t_{PLH}) are determined by the rising edge rate of the input signal, the ONE-SHOT accelerator's pull-up capability, and the capacitive load of the port. The falling edge time of the signal (t_{fA} , t_{fB}) depends on the falling edge rate of the input signal, the output impedance of the external driver, and the capacitive load on the data line. Similarly, t_{PHL} and the maximum data rate also depend on the output impedance of the external driver. So, the test conditions for t_{rA} , t_{rB} , t_{rA} , t_{rB} , t_{PLH} , t_{PHL} and maximum data rate in the data sheet are that the output impedance of the external driver is less than 50 Ω .



Output Load

It is recommended that a PCB layout with short PCB layout length:

- 1. Avoid excessive capacitive load triggers ONE-SHOT circuit falsely;
- 2. It can ensure that the round trip delay of any reflection is less than a single ONE-SHOT duration;
- 3. Improve signal integrity.

Meanwhile, the pulse width of the ONE-SHOT circuit is approximately 30 ns, which determines the maximum output load capacitance that the chip can drive. For very heavy output capacitive loads, the one-shot accelerator will time-out before the output is fully pulled to high level, at which case the signal transmission will be distorted. So the ONE-SHOT duration design requires a trade-off between dynamic power consumption, capacitive load driving capability and maximum data rate. The signal tw at the maximum translation rate should be greater than the maximum pulse width of the ONE-SHOT circuit, and the delay caused by the output capacitive load should be less than the maximum pulse width of the ONE-SHOT circuit.



Application Information

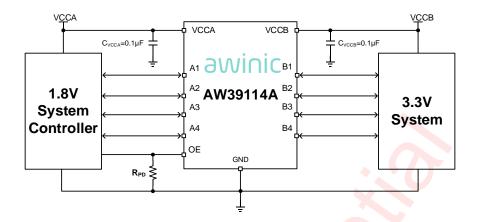


Figure 14 AW39114A Application Circuit

AW39114A is a 4-bit voltage-level translator without direction control signal, which is suitable for interfacing devices or systems operating at different interface voltages with one another. Port A can supports I/O voltages from 1.1 V to 3.6 V, while Port B is able to support I/O voltage range from 1.65 V to 5.5 V. Also, $10k\Omega$ pull-up resistors are integrated in the chip, which ensures the chip not only supports push-pull applications but also can be used in open-drain applications directly.

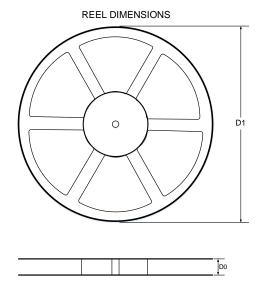
VCC Capacitor Selection

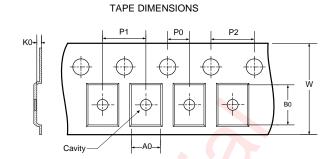
The device is a 4-bit high-performance voltage-level translator that requires adequate power supply decoupling. Place a low equivalent-series-resistance (ESR) ceramic capacitor, recommend 0.1µF or larger than 0.1µF.

RPD Selection

Drive OE pin HIGH to enable the device. If the voltage level of OE pin is low, all I/O are pulled to the supply voltage through a $5M\Omega$ internal pull-up resistor. OE is recommended to be tied to GND through an external pull-down resistor to ensure the ultra-low power-supply quiescent current. OE pin is high impedance without internal pull down resistor, customer can choose the resistor value based on the source drive capability and current consumption.

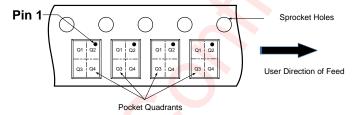
Tape And Reel Information





- A0: Dimension designed to accommodate the component width
- B0: Dimension designed to accommodate the component length
- K0: Dimension designed to accommodate the component thickness
- W: Overall width of the carrier tape
- P0: Pitch between successive cavity centers and sprocket hole
- P1: Pitch between successive cavity centers
- P2: Pitch between sprocket hole
- D1: Reel Diameter
 D0: Reel Width

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



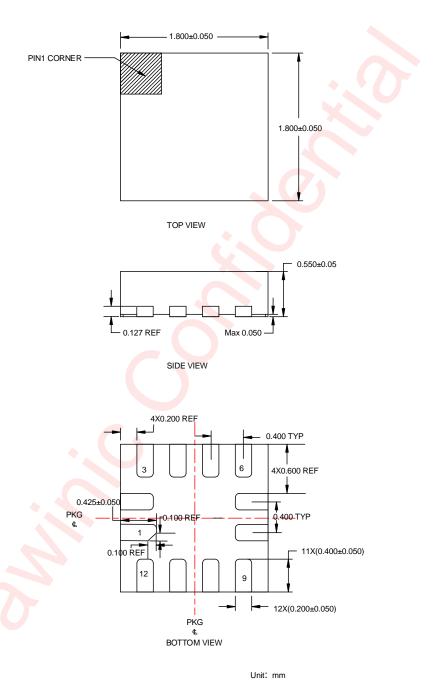
Note: The above picture is for reference only. Please refer to the value in the table below for the actual size

DIMENSIONS AND PIN1 ORIENTATION

_			_							
D1	D0	_	B0	_	-	P1			Pin1 Quadrant	
(mm)										
178	8.4	2.06	2.06	0.73	2	4	4	8	Q2	

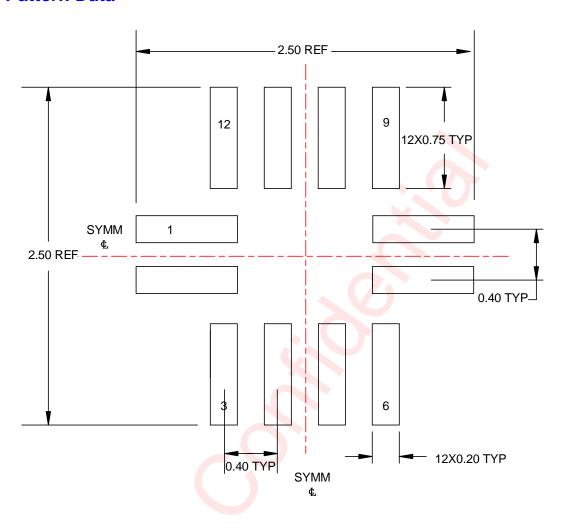
All dimensions are nominal

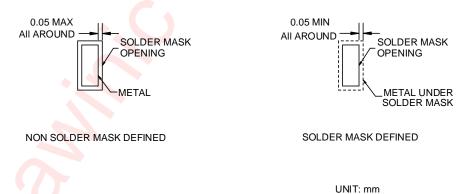
Package Description(POD)





Land Pattern Data







Revision History

Version	Date	Change Record			
V1.0	Jul. 2022	Official Released			





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